# FAIRCHILD

SEMICONDUCTOR®

# FDB8444\_F085

# N-Channel PowerTrench<sup>®</sup> MOSFET 40V, 70A, 5.5m $\Omega$

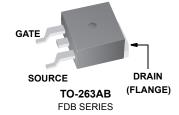
# Features

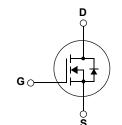
- Typ  $r_{DS(on)}$  = 3.9m $\Omega$  at V<sub>GS</sub> = 10V, I<sub>D</sub> = 70A
- Typ  $Q_{g(TOT)}$  = 91nC at V<sub>GS</sub> = 10V
- Low Miller Charge
- Low Q<sub>rr</sub> Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant

# Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Transmission
- Distributed Power Architecture and VRMs
- Primary Switch for 12V Systems







October 2010

Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain to Source Voltage		40	V
/ <sub>GS</sub>	Gate to Source Voltage		± 20	V
	Drain Current Continuous (V <sub>GS</sub> = 10V)	(Note 1)	70	А
D	Pulsed		Figure 4	
AS	Single Pulse Avalanche Energy	(Note 2)	307	mJ
, ,	Power Dissipation		167	W
D	Derate above 25°C		1.1	W/ºC
J, T <sub>STG</sub>	Operating and Storage Temperature		-55 to +175	°C

# **Thermal Characteristics**

$R_{ ext{ heta}JC}$	Maximum Thermal Resistance, Junction to Case	0.9	°C/W
$R_{ hetaJA}$	Maximum Thermal Resistance, Junction to Ambient TO-263, lin <sup>2</sup> copper pad area	43	°C/W

# Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB8444	FDB8444_F085	TO-263AB	330mm	24mm	800 units

# Electrical Characteristics T<sub>J</sub> = 25°C unless otherwise noted

	Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
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# **Off Characteristics**

B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>G</sub>	$I_{D}$ = 250µA, $V_{GS}$ = 0V		-	-	V
I <sub>DSS</sub> Zero Gate Voltage Drain Current		V <sub>DS</sub> = 32V		-	-	1	μA
DSS	Zero Gale voltage Drain Current	$V_{GS} = 0V$	T <sub>J</sub> =150°C	-	-	250	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS}$ = $\pm 20V$		-	-	±100	nA

### **On Characteristics**

V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	2	2.6	4	V
		I <sub>D</sub> = 70A, V <sub>GS</sub> = 10V	-	3.9	5.5	
r <sub>DS(on)</sub>	Drain to Source On Resistance	$I_D = 70A, V_{GS} = 10V,$ $T_J = 175^{\circ}C$	-	7	9.9	mΩ

## **Dynamic Characteristics**

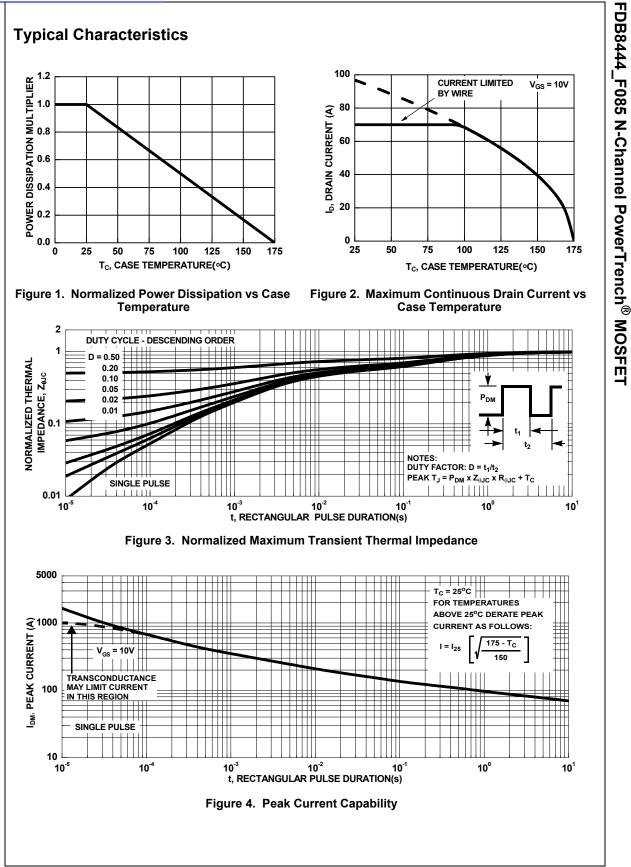
C <sub>iss</sub>	Input Capacitance			-	6040	8035	pF
C <sub>oss</sub>	Output Capacitance		- V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, - f = 1MHz		480	640	pF
C <sub>rss</sub>	Reverse Transfer Capacitance				290	435	pF
R <sub>G</sub>	Gate Resistance	f = 1MHz		-	2	-	Ω
Q <sub>g(TOT)</sub>	Total Gate Charge at 10V	V <sub>GS</sub> = 0 to 10V		-	91	128	nC
Q <sub>g(TH)</sub>	Threshold Gate Charge	$V_{GS}$ = 0 to 2V	V <sub>DD</sub> =20V,	-	7	10	nC
Q <sub>gs</sub>	Gate to Source Gate Charge		I <sub>D</sub> = 70A,	-	23	-	nC
Q <sub>gs2</sub>	Gate Charge Threshold to Plateau			-	17	-	nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			-	20	-	nC

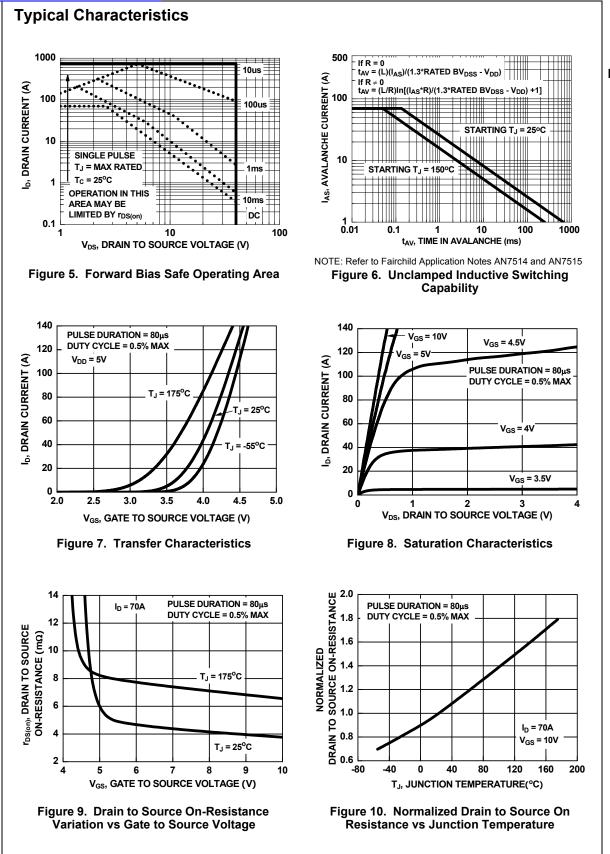
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switching	J Characteristics					
t <sub>(on)</sub>	Turn-On Time		-	-	135	ns
t <sub>d(on)</sub>	Turn-On Delay Time	V <sub>DD</sub> = 20V, I <sub>D</sub> = 70A	-	12	-	ns
t <sub>r</sub>	Turn-On Rise Time		-	78	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{DD} = 20V, I_D = 70A$ $V_{GS} = 10V, R_{GS} = 2\Omega$	-	48	-	ns
ł	Turn-Off Fall Time		-	15	-	ns
t <sub>off</sub>	Turn-Off Time		-	-	95	ns

V <sub>SD</sub> Source to Drain Diode Voltage		I <sub>SD</sub> = 70A	-	-	1.25	V
		I <sub>SD</sub> = 35A	-	-	1.0	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 70A, di/dt = 100A/μs	-	-	62	ns
Q <sub>rr</sub>	Reverse Recovery Charge	I <sub>F</sub> = 70A, di/dt = 100A/μs	-	-	82	nC

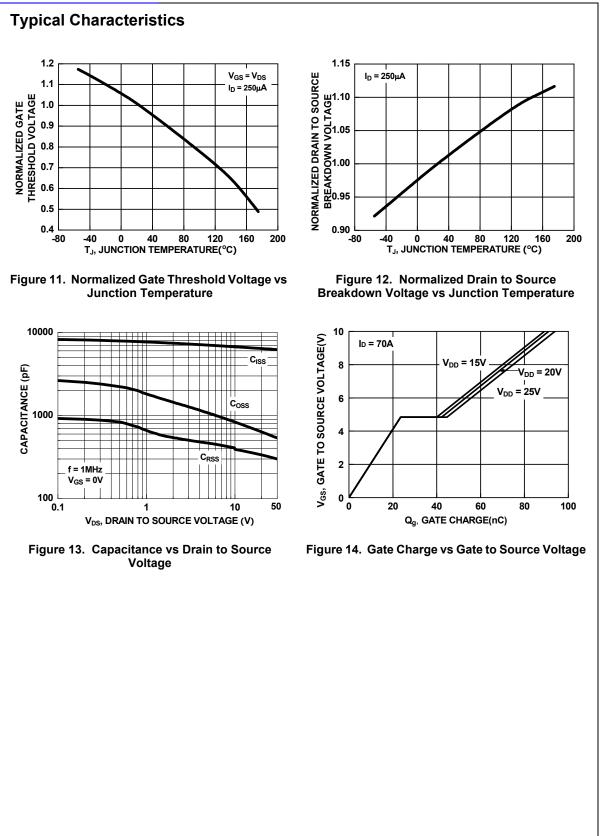
Notes: 1: Maximum wire current carrying capacity is 70A. 2: Starting  $T_J = 25^{\circ}C$ , L = 0.2mH,  $I_{AS} = 56A$ .

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.





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-	Formative / In Design First Production Full Production